

1.Description

Designed to protect voltage sensitive electronic components from ESD and other transients. Excellent clamping capability, low leakage, low capacitance, and fast response time provide best in class protection on designs that are exposed to ESD.

3.Applications

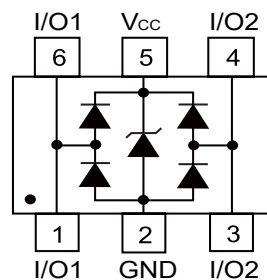
- USB3.0 power & data line protection
- WLAN/LAN equipment
- Mobile phone
- Video line protection

2.Features

- Uni-directional ESD protection of two lines
- Low capacitance: 0.8pF(Max)
- Low reverse stand-off voltage: 5V
- Low reverse clamping voltage
- Low leakage current
- Excellent package: 2.92mm×1.60mm×1.1mm
- Fast response time

- Microcontroller input Protection
- ISDN S/T Interface
- Other electronics equipments
- Communication systems

4.Pinning information



SOT23-6



5. Absolute Maximum Ratings $T_A = 25^\circ\text{C}$

Parameter	Symbol	Maximum	Units
IEC 61000-4-2 ESD Voltage	$V_{\text{ESD}(1)}$	± 25	kV
Air Model			
Contact Model		± 25	kV
JESD22-A114-B ESD Voltage		± 16	kV
Per Human Body Model			
ESD Voltage		± 0.4	kV
Machine Model			
Peak Pulse Power	$P_{\text{pp}(2)}$	90	W
Peak Pulse Current	$I_{\text{pp}(2)}$	3.5	A
Lead Solder Temperature – Maximum (10 Second Duration)	T_L	260	$^\circ\text{C}$
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	$^\circ\text{C}$

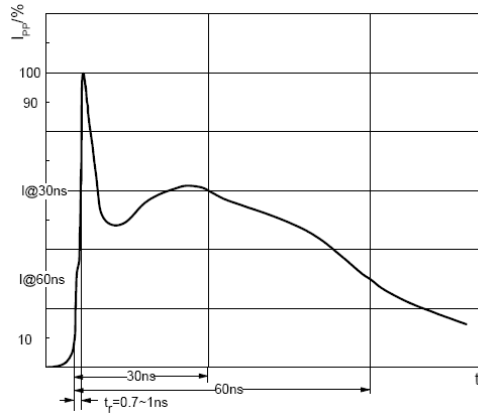
Notes:

(1) Device stressed with ten non-repetitive ESD pulses.

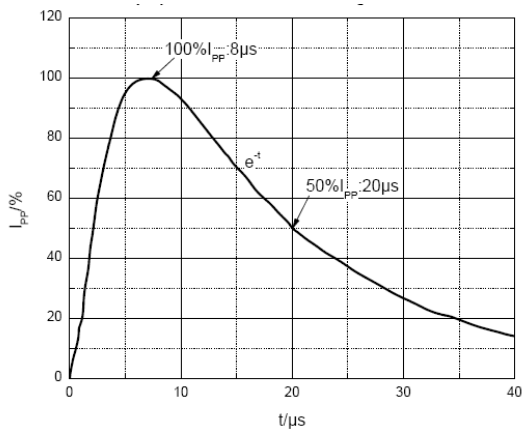
(2) Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC61000-4-5



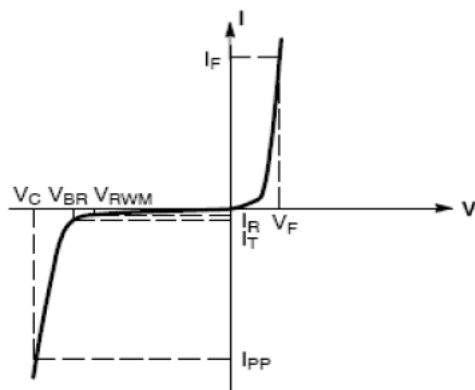
6.ESD standards compliance



ESD pulse waveform according to IEC61000-4-2



8/20μs pulse waveform according to IEC 61000-4-5



V-I characteristics for a uni-directional TVS

Contact Discharge		Air Discharge	
Level	Test Voltage kV	Level	Test Voltage kV
1	2	1	2
2	4	2	4
3	6	3	8
4	8	4	15

ESD Class	Human Body Discharge V
0	0 ~ 249
1A	250 ~ 499
1B	500 ~ 999
1C	1000 ~ 1999
2	2000 ~ 3999
3A	4000 ~ 7999
3B	8000 ~ 15999

Symbol	Parameter
V_C	Clamping Voltage @ I_{PP}
I_{PP}	Peak Pulse Current
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_R	Reverse Leakage Current @ V_{RWM}
V_{RWM}	Reverse Standoff Voltage
V_F	Forward Voltage @ I_F
I_F	Forward Current



7. Electrical Characteristic ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Per channel(I/O to GND unless otherwise specified)						
Reverse stand off voltage	$V_{RWM(1)}$	Any I/O pin to GND			5	V
Breakdown voltage	$V_{(BR)}$	$I_T=1\text{mA}$	6		10	V
		$I_T=1\text{mA}, V_{CC}$ to GND	5		12	V
Reverse leakage current	I_R	$V_{RWM}=5\text{V}$ (I/O to GND & V_{CC} to GND)			1	μA
Forward voltage	V_F	$I_F=10\text{mA}$ (GND to I/O & GND to V_{CC})	0.4		1.5	V
Clamping voltage	$V_{C(2)}$	$I_{PP}=1\text{A}$ (I/O to GND & V_{CC} to GND)			13	V
		$I_{PP}=3.5\text{A}$ (I/O to GND & V_{CC} to GND)			25	V
Junction capacitance	C_J	$V_R=0\text{V}, f=1\text{MHz}$			0.8	pF
		$V_R=0\text{V}, f=1\text{MHz}, \text{I/O to I/O}$			0.4	pF

Notes:

(1).Other voltages available upon request.

(2).Non-repetitive current pulse 8/20 μs exponential decay waveform

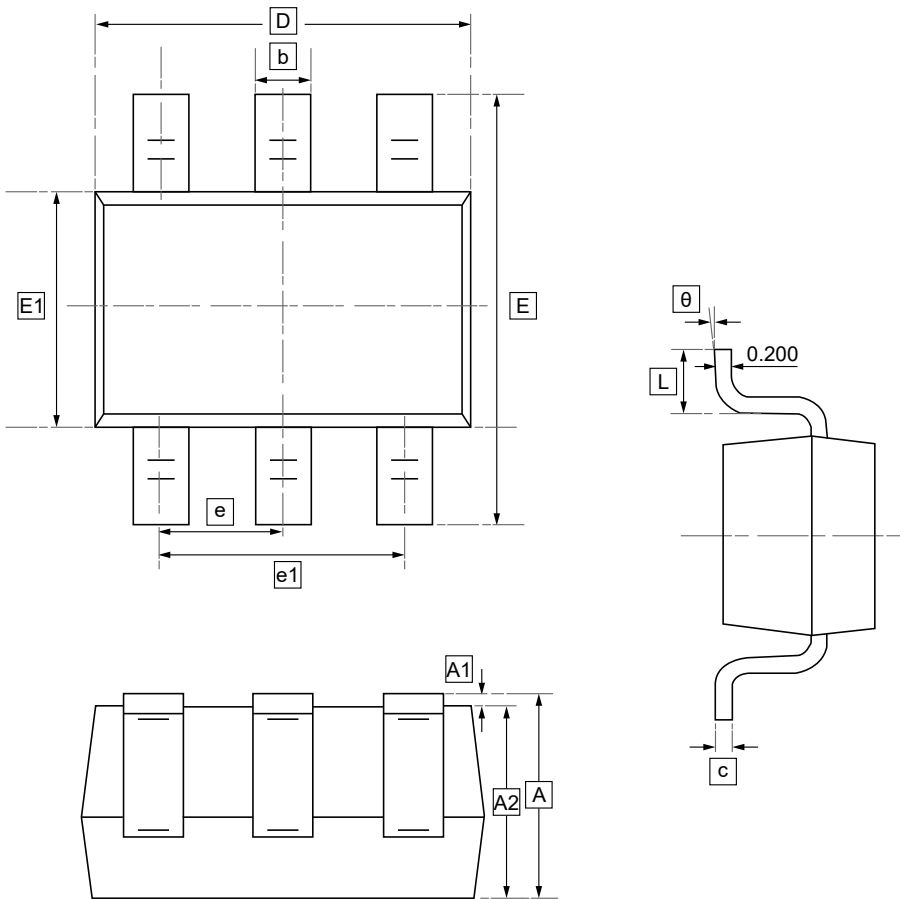


8. Typical characteristic

Figure 1: Forward Characteristics	Figure 2: Forward Characteristics
Figure 3: Reverse Characteristics	Figure 4: Reverse Characteristics
Figure 5: V_C — I_{PP}	Figure 6: Capacitance Characteristics



9.SOT-23-6 Package Outline Dimensions

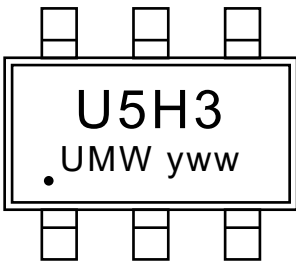


DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	c	D	E1	E	e	e1	L	θ
Min	1.050	0.000	1.050	0.300	0.100	2.820	1.500	2.650	0.950	1.800	0.300	0°
Max	1.250	0.100	1.150	0.500	0.200	3.020	1.700	2.950	BSC	2.000	0.600	8°



10.Ordering information



yww: Batch Code

Order Code	Package	Base QTY	Delivery Mode
UMW ESDU5V0H3	SOT23-6	3000	Tape and reel



11.Disclaimer

UMW reserves the right to make changes to all products, specifications. Customers should obtain the latest version of product documentation and verify the completeness and currency of the information before placing an order.

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